

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S67	10	"20030147601" "20030186674" "20030090320" "20030124984" "20030113059"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/12 08:36
S68	1	triplexer with laser with photodiode with substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:10
S69	1	triplexer with laser with photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/04 16:18
S70	1158	laser with photodiode with substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/04 16:19
S71	275	laser with photodiode with substrate and "385"/\$.cls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/04 16:19
S72	9	\$plexer with laser with photodiode with substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/04 17:09
S73	234	transistor adj outline	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:11
S75	2	((transistor adj outline) or (TO adj (package or can))) with laser with photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:16
S76	6470	(vertical adj cavity adj surface adj emitting adj laser) or vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:17
S77	517	((vertical adj cavity adj surface adj emitting adj laser) or vcsel) with photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:18

S79	105	((vertical adj cavity adj surface adj emitting adj laser) or vcsel) with photodiode with substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:18
S80	100	S79 not @ad>="20040310"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:19
S82	18	S80 and \$5plexer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:31
S85	2	triplex\$3 and photodiode and substrate and ((vertical adj cavity adj surface adj emitting adj laser) or vcsel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:36
S88	237	photodiode and InGaAs and substrate and ((vertical adj cavity adj surface adj emitting adj laser) or vcsel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:39
S90	157	photodiode and InGaAs same substrate and ((vertical adj cavity adj surface adj emitting adj laser) or vcsel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:40
S91	82	photodiode and InGaAs with substrate and ((vertical adj cavity adj surface adj emitting adj laser) or vcsel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:48
S93	20	photodiode and InGaAs near3 substrate and ((vertical adj cavity adj surface adj emitting adj laser) or vcsel)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:48
S94	19	S93 not @ad>="20040310"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:55
S95	3831	385/14.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:55

S96	1	385/14.ccls. and triplexer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:56
S97	70	385/14.ccls. and photodiode with laser with substrate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 09:57
S98	42	385/14.ccls. and photodiode with laser with substrate and \$5plex\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 11:32
S99	387	(laser with nm) same (photodiode with nm)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 11:36
S10 2	29	(laser with nm) same (photodiode with nm) same ("1310" "1490" "1550")	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 15:25
S10 4	4	"20030026515" "6220764".pn.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/05 16:10
S10 8	925	semiconductor with laser with ingaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:19
S11 0	5	S108 with multiplex\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:21
S11 1	1386	372/96.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:21
S11 2	458	372/96.ccls. and vcsel	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:22

S11 3	32	372/96.ccls. and vcsel with photodiode	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:25
S11 4	5	372/96.ccls. and vcsel with photodiode and multiplex\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:31
S11 5	87	vcsl with "1310"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:32
S11 6	3	vcsl with "1310" with ingaas	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:41
S11 7	1411	photodiode with ((another or second) adj photodiode)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 13:41
S11 8	170	photodiode with ((another or second) adj photodiode) with laser	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 15:10
S12 0	146	photodiode with cutoff	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 15:10
S12 1	2	photodiode with cutoff with dop\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/10 15:11
S12 2	14	((ingaas with substrate) same (semiconductor with laser)) and multiplexer	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	ON	2005/05/12 08:38